Hall IC Series / Hall IC(Latch type)

Pb Free
ROHM Electronic Components

Bipolar Detection Hall ICs

BU52001GUL, BU52011HFV, BU52021HFV, BU52015GUL, BU52025G, BU52051NVX, BD7411G

● Description

The bipolar Hall ICs are magnetic switches that can operate both S-and N-pole , upon which the output goes from Hi to Low. In addition to regular single-output Hall ICs, We offers a line up of dual-output units with a reverse output terminal (active High).

● Features

1) Bipolar detection
2) Micropower operation (small current using intermittent operation method)(BD7411G is excluded.)
3) Ultra-compact CSP4 package (BU52001GUL,BU52015GUL)
4) Ultra-Small outline package HVSOF5 (BU52011HFV,BU52021HFV)
5) Ultra-Small outline package SSON004X1216 (BU52051NVXV)
6) Small outline package (BU52025G,BD7411G）
7) Line up of supply voltage
    For 1.8V Power supply voltage （BU52011HFV,BU52015GUL,BU52051NVX)
    For 3.0V Power supply voltage (BU52001GUL)
    For 3.3V Power supply voltage (BU52021HFV,BU52025G)
    For 5.0V Power supply voltage (BD7411G)
8) Dual output type (BU52015GUL)
9) High ESD resistance 8kV(HBM)

● Applications

Mobile phones, notebook computers, digital video camera, digital still camera, white goods etc.

● Product Lineup

Product name	Supply voltage (V)	Operate point (mT)	Hysteresis (mT)	Period (ms)	Supply current (AVG) (A)	Output type	Package
BU52001GUL	2.40～3.30	+/-3.7 ※	0.8	50	8.0μ	CMOS	VCSP50L1
BU52015GUL	1.65～3.30	+/-3.0 ※	0.9	50	5.0μ	CMOS	VCSP50L1
BU52051NVX	1.65～3.30	+/-3.0 ※	0.9	50	5.0μ	CMOS	SSON004X1216
BU52011HFV	1.65～3.30	+/-3.0 ※	0.9	50	5.0μ	CMOS	HVSOF5
BU52021HFV	2.40～3.60	+/-3.7 ※	0.8	50	8.0μ	CMOS	HVSOF5
BU52025G	2.40～3.60	+/-3.7 ※	0.8	50	8.0μ	CMOS	SSOP5
BD7411G	4.50～5.50	+/-3.4 ※	0.4	-	2.0m	CMOS	SSOP5

※Plus is expressed on the S-pole; minus on the N-pole

Aug. 2008

●Absolute Maximum Ratings

BU52001GUL (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.1～+4.5[※1]	V
Output Current	I_{OUT}	±1	mA
Power Dissipation	Pd	420[※2]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-40～+125	℃

※1. Not to exceed Pd
※2. Reduced by 4.20mW for each increase in Ta of 1℃ over 25℃
（mounted on 50mm×58mm Glass-epoxy PCB）

BU52015GUL (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.1～+4.5[※3]	V
Output Current	I_{OUT}	±0.5	mA
Power Dissipation	Pd	420[※4]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-40～+125	℃

※3. Not to exceed Pd
※4. Reduced by 4.20mW for each increase in Ta of 1℃ over 25℃
（mounted on 50mm×58mm Glass-epoxy PCB）

BU52051NVX (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.1～+4.5[※5]	V
Output Current	I_{OUT}	±0.5	mA
Power Dissipation	Pd	2049[※6]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-40～+125	℃

※5. Not to exceed Pd
※6. Reduced by 20.49mW for each increase in Ta of 1℃ over 25℃
（mounted on 70mm×70 mm×1.6mm Glass-epoxy PCB）

BU52011HFV (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.1～+4.5[※7]	V
Output Current	I_{OUT}	±0.5	mA
Power Dissipation	Pd	536[※8]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-40～+125	℃

※7. Not to exceed Pd
※8. Reduced by 5.36mW for each increase in Ta of 1℃ over 25℃
（mounted on 70mm×70 mm×1.6mm Glass-epoxy PCB）

BU52021NVX (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.1～+4.5[※9]	V
Output Current	I_{OUT}	±1	mA
Power Dissipation	Pd	536[※10]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-40～+125	℃

※9. Not to exceed Pd
※10. Reduced by5.36mW for each increase in Ta of 1℃ over 25℃
（mounted on 70mm×70 mm×1.6mm Glass-epoxy PCB）

BU52025G (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.1～+4.5[※11]	V
Output Current	I_{OUT}	±1	mA
Power Dissipation	Pd	540[※12]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-40～+125	℃

※11. Not to exceed Pd
※12. Reduced by 5.40mW for each increase in Ta of 1℃ over 25℃
（mounted on 70mm×70 mm×1.6mm Glass-epoxy PCB）

BD7411G (Ta=25℃)

PARAMETERS	SYMBOL	LIMIT	UNIT
Power Supply Voltage	V_{DD}	-0.3～+7.0[※13]	V
Output Current	I_{OUT}	±1	mA
Power Dissipation	Pd	540[※14]	mW
Operating Temperature Range	T_{opr}	-40～+85	℃
Storage Temperature Range	T_{stg}	-55～+150	℃

※13. Not to exceed Pd
※14. Reduced by 5.40mW for each increase in Ta of 1℃ over 25℃
（mounted on 70mm×70 mm×1.6mm Glass-epoxy PCB）

●Magnetic, Electrical Characteristics

BU52001GUL (Unless otherwise specified, V_{DD}＝3.0V, Ta＝25℃)

PARAMETERS	SYMBOL	LIMIT			UNIT	CONDITIONS
		MIN	TYP	MAX		
Power Supply Voltage	V_{DD}	2.4	3.0	3.3	V	
Operate Point	B_{opS}	-	3.7	5.5	mT	
	B_{opN}	-5.5	-3.7	-		
Release Point	B_{rpS}	0.8	2.9	-	mT	
	B_{rpN}	-	-2.9	-0.8		
Hysteresis	B_{hysS}	-	0.8	-	mT	
	B_{hysN}	-	0.8	-		
Period	T_p	-	50	100	ms	
Output High Voltage	V_{OH}	V_{DD} -0.4	-	-	V	$B_{rpN}<B<B_{rpS}$ ※15 I_{OUT} =-1.0mA
Output Low Voltage	V_{OL}	-	-	0.4	V	$B<B_{opN}, B_{opS}<B$ ※15 I_{OUT} =+1.0mA
Supply Current	$I_{DD(AVG)}$	-	8	12	μA	Average
Supply Current During Startup Time	$I_{DD(EN)}$	-	4.7	-	mA	During Startup Time Value
Supply Current During Standby Time	$I_{DD(DIS)}$	-	3.8	-	μA	During Standby Time Value

※15 B = Magnetic flux density

1mT=10Gauss

Positive ("+") polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.

After applying power supply, it takes one cycle of period (T_P) to become definite output.

Radiation hardiness is not designed.

BU52015GUL (Unless otherwise specified, V_{DD}＝1.80V, Ta＝25℃)

PARAMETERS	SYMBOL	LIMIT			UNIT	CONDITIONS
		MIN	TYP	MAX		
Power Supply Voltage	V_{DD}	1.65	1.80	3.30	V	
Operate Point	B_{opS}	-	3.0	5.0	mT	
	B_{opN}	-5.0	-3.0	-		
Release Point	B_{rpS}	0.6	2.1	-	mT	
	B_{rpN}	-	-2.1	-0.6		
Hysteresis	B_{hysS}	-	0.9	-	mT	
	B_{hysN}	-	0.9	-		
Period	T_p	-	50	100	ms	
Output High Voltage	V_{OH}	V_{DD} -0.2	-	-	V	OUT1: $B_{rpN}<B<B_{rpS}$ ※16 OUT2: $B<B_{opN}$, $B_{opS}<B$ I_{OUT} = -0.5mA
Output Low Voltage	V_{OL}	-	-	0.2	V	OUT1: $B<B_{opN}$, $B_{opS}<B$ ※16 OUT2: $B_{rpN}<B<B_{rpS}$ I_{OUT} = +0.5mA
Supply Current 1	$I_{DD1(AVG)}$	-	5	8	μA	V_{DD}=1.8V, Average
Supply Current During Startup Time 1	$I_{DD1(EN)}$	-	2.8	-	mA	V_{DD}=1.8V, During Startup Time Value
Supply Current During Standby Time 1	$I_{DD1(DIS)}$	-	1.8	-	μA	V_{DD}=1.8V, During Standby Time Value
Supply Current 2	$I_{DD2(AVG)}$	-	8	12	μA	V_{DD}=2.7V, Average
Supply Current During Startup Time 2	$I_{DD2(EN)}$	-	4.5	-	mA	V_{DD}=2.7V, During Startup Time Value
Supply Current During Standby Time 2	$I_{DD2(DIS)}$	-	4.0	-	μA	V_{DD}=2.7V, During Standby Time Value

※16 B = Magnetic flux density

1mT=10Gauss

Positive ("+") polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.

After applying power supply, it takes one cycle of period (T_P) to become definite output.

Radiation hardiness is not designed.

BU52051NVX , BU52011HFV (Unless otherwise specified, V_{DD}＝1.80V, Ta＝25℃)

PARAMETERS	SYMBOL	LIMIT			UNIT	CONDITIONS
		MIN	TYP	MAX		
Power Supply Voltage	V_{DD}	1.65	1.80	3.30	V	
Operate Point	B_{opS}	-	3.0	5.0	mT	
	B_{opN}	-5.0	-3.0	-		
Release Point	B_{rpS}	0.6	2.1	-	mT	
	B_{rpN}	-	-2.1	-0.6		
Hysteresis	B_{hysS}	-	0.9	-	mT	
	B_{hysN}	-	0.9	-		
Period	T_p	-	50	100	ms	
Output High Voltage	V_{OH}	V_{DD} -0.2	-	-	V	$B_{rpN}<B<B_{rpS}$ ※17 I_{OUT} =-0.5mA
Output Low Voltage	V_{OL}	-	-	0.2	V	$B<B_{opN}$, $B_{opS}<B$ ※17 I_{OUT} =+0.5mA
Supply Current 1	$I_{DD1(AVG)}$	-	5	8	μA	V_{DD}=1.8V, Average
Supply Current During Startup Time 1	$I_{DD1(EN)}$	-	2.8	-	mA	V_{DD}=1.8V, During Startup Time Value
Supply Current During Standby Time 1	$I_{DD1(DIS)}$	-	1.8	-	μA	V_{DD}=1.8V, During Standby Time Value
Supply Current 2	$I_{DD2(AVG)}$	-	8	12	μA	V_{DD}=2.7V, Average
Supply Current During Startup Time 2	$I_{DD2(EN)}$	-	4.5	-	mA	V_{DD}=2.7V, During Startup Time Value
Supply Current During Standby Time 2	$I_{DD2(DIS)}$	-	4.0	-	μA	V_{DD}=2.7V, During Standby Time Value

BU52021HFV,BU52025G (Unless otherwise specified, V_{DD}＝3.0V, Ta＝25℃)

PARAMETERS	SYMBOL	LIMIT			UNIT	CONDITIONS
		MIN	TYP	MAX		
Power Supply Voltage	V_{DD}	2.4	3.0	3.6	V	
Operate Point	B_{opS}	-	3.7	5.5	mT	
	B_{opN}	-5.5	-3.7	-		
Release Point	B_{rpS}	0.8	2.9	-	mT	
	B_{rpN}	-	-2.9	-0.8		
Hysteresis	B_{hysS}	-	0.8	-	mT	
	B_{hysN}	-	0.8	-		
Period	T_p	-	50	100	ms	
Output High Voltage	V_{OH}	V_{DD} -0.4	-	-	V	$B_{rpN}<B<B_{rpS}$ ※17 I_{OUT} =-1.0mA
Output Low Voltage	V_{OL}	-	-	0.4	V	$B<B_{opN}$, $B_{opS}<B$ ※17 I_{OUT} =+1.0mA
Supply Current	$I_{DD(AVG)}$	-	8	12	μA	Average
Supply Current During Startup Time	$I_{DD(EN)}$	-	4.7	-	mA	During Startup Time Value
Supply Current During Standby Time	$I_{DD(DIS)}$	-	3.8	-	μA	During Standby Time Value

※17 B = Magnetic flux density
1mT=10Gauss
Positive ("+") polarity flux is defined as the magnetic flux from south pole which is direct toward to the branded face of the sensor.
After applying power supply, it takes one cycle of period (T_P) to become definite output.
Radiation hardiness is not designed.

BD7411G (Unless otherwise specified, V_{DD}＝5.0V, Ta＝25℃)

PARAMETERS	SYMBOL	LIMIT			UNIT	CONDITIONS
		MIN	TYP	MAX		
Power Supply Voltage	V_{DD}	4.5	5.0	5.5	V	
Operate Point	B_{opS}	-	3.4	5.6	mT	
	B_{opN}	-5.6	-3.4	-		
Release Point	B_{rpS}	1.5	3.0	-	mT	
	B_{rpN}	-	-3.0	-1.5		
Hysteresis	B_{hysS}	-	0.4	-	mT	
	B_{hysN}	-	0.4	-		
Output High Voltage	V_{OH}	4.6	-	-	V	$B_{rpN}<B<B_{rpS}$ ※18 $I_{OUT} =-1.0mA$
Output Low Voltage	V_{OL}	-	-	0.4	V	$B<B_{opN}$, $B_{opS}<B$ ※18 $I_{OUT} =+1.0mA$
Supply Current	I_{DD}	-	2	4	mA	

※18 B = Magnetic flux density
1mT=10Gauss
Positive ("+") polarity flux is defined as the magnetic flux from south pole which is direct toward to
the branded face of the sensor.
Radiation hardiness is not designed.

●Figure of measurement circuit

B_{op}/B_{rp}

Bop and Brp are measured with applying the magnetic field from the outside.
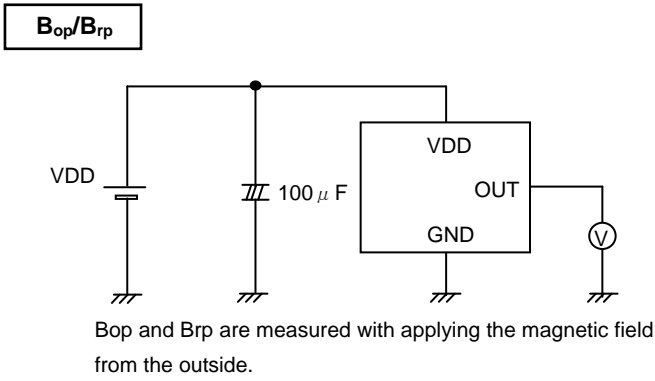
Fig.1 B_{op}, B_{rp} measurement circuit

T_p

The period is monitored by Oscilloscope.
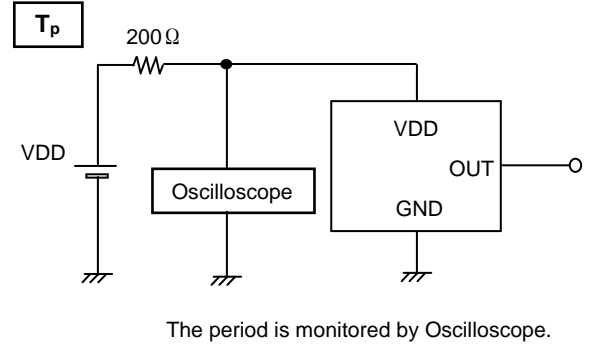
Fig.2 T_p measurement circuit

V_{OH}
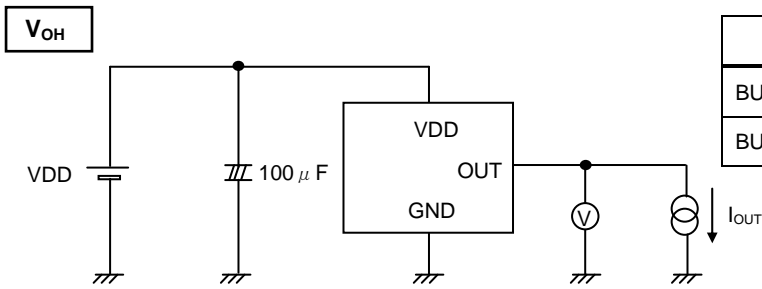
Fig.3 V_{OH} measurement circuit

Product Name	I_{OUT}
BU52001GUL, BU52021HFV, BU52025G, BD7411G	1.0mA
BU52015GUL, BU52051NVX, BU52011HFV	0.5mA

V_{OL}
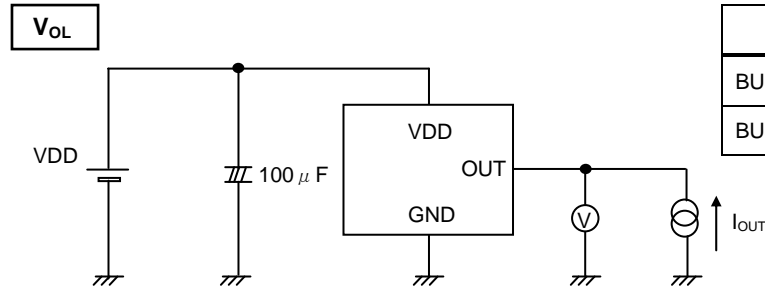
Fig.4 V_{OL} measurement circuit

Product Name	I_{OUT}
BU52001GUL, BU52021HFV, BU52025G, BD7411G	1.0mA
BU52015GUL, BU52051NVX, BU52011HFV	0.5mA

I_{DD}
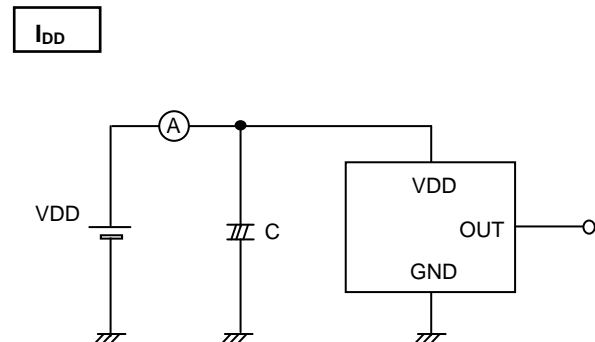
Fig.5 I_{DD} measurement circuit

Product Name	C
BU52001GUL,BU52015GUL,BU52051NVX, BU52011HFV, BU52021HFV, BU52025G	2200 μ F
BD7411G	100 μ F

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● Technical (Reference) Data

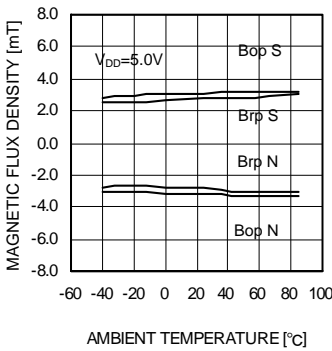**BU52001GUL (V$_{DD}$=2.4～3.3V type)**
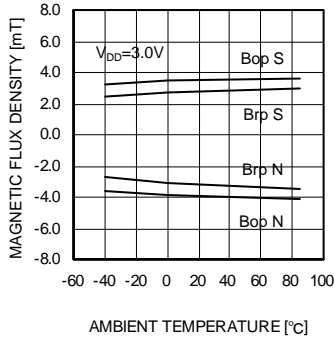
Fig.6　Bop,Brp–
Ambient temperature
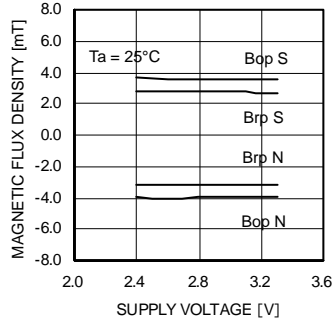
Fig.7　Bop,Brp– Supply voltage
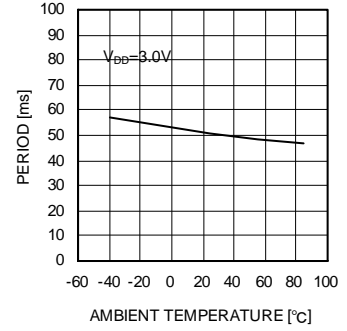
Fig.8　T$_P$– Ambient
temperature
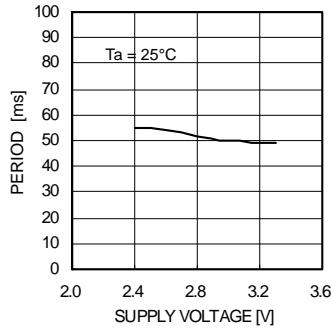
Fig.9　T$_P$– Supply voltage
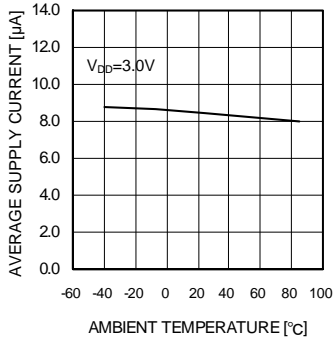
Fig.10　I$_{DD}$– Ambient
temperature
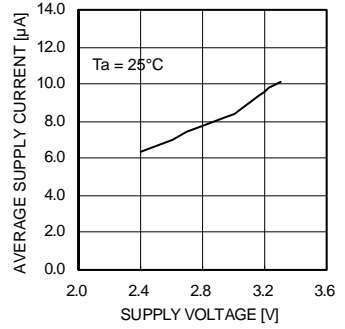
Fig.11　I$_{DD}$ – Supply voltage

BU52015GUL, BU52051NVX, BU52011HFV (V$_{DD}$=1.65～3.3V type)
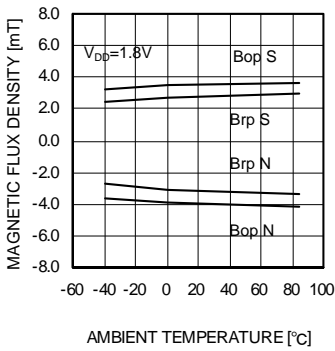
Fig.12　Bop,Brp–
Ambient temperature
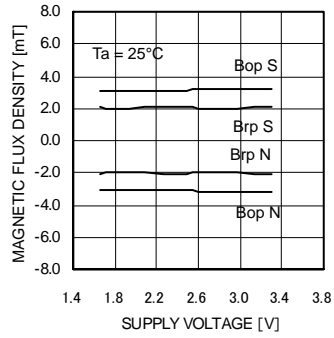
Fig.13　Bop,Brp– Supply voltage
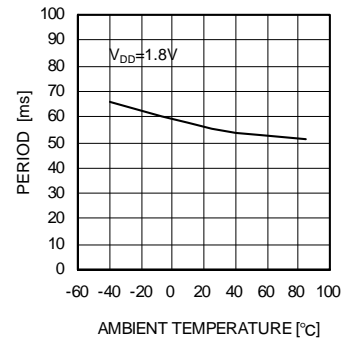
Fig.14　T$_P$ – Ambient
temperature
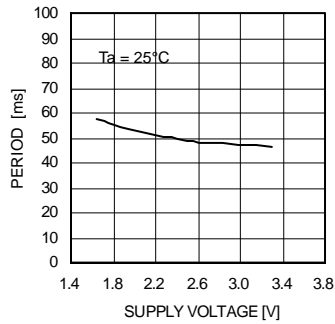
Fig.15　T$_P$– Supply voltage
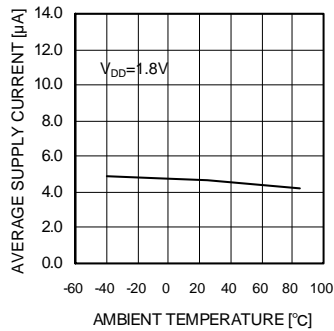
Fig.16　I$_{DD}$– Ambient
temperature
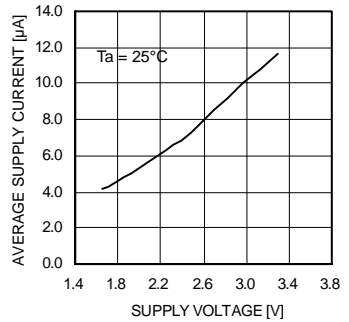
Fig.17　I$_{DD}$ – Supply voltage

BU52021HFV, BU52025G (V$_{DD}$=2.4～3.6V type)
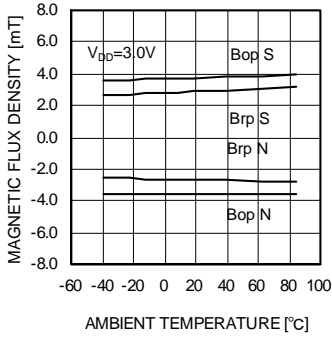
Fig.18　Bop,Brp–
Ambient temperature
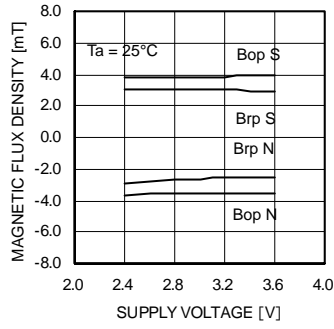
Fig.19　Bop,Brp– Supply voltage
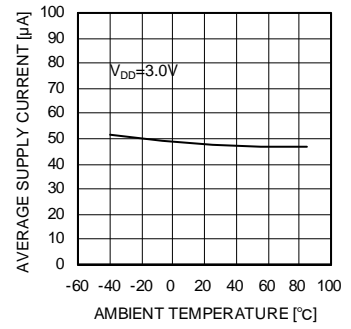
Fig.20　T$_P$ – Ambient
temperature
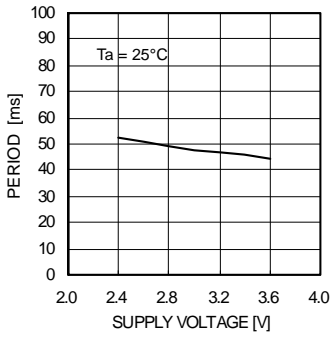
Fig.21　T$_P$ – Supply voltage
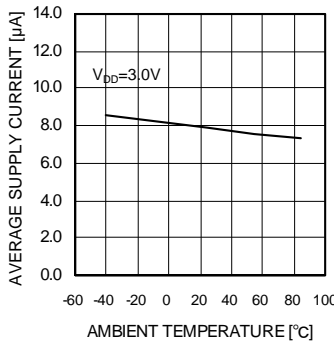
Fig.22　I$_{DD}$ – Ambient
temperature
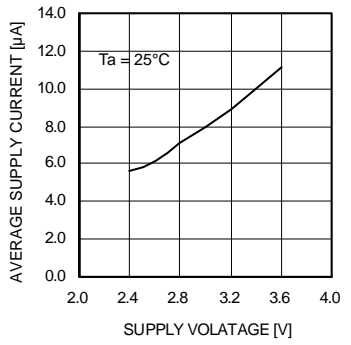
Fig.23　I$_{DD}$ – Supply voltage

BD7411G (V$_{DD}$=4.5～5.5V type)

Fig.24　Bop,Brp–
Ambient temperature
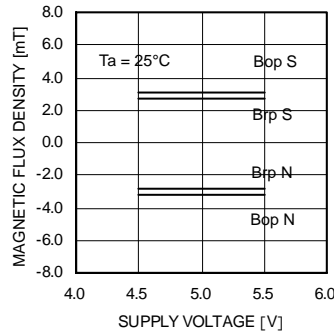
Fig.25　Bop,Brp– Supply voltage
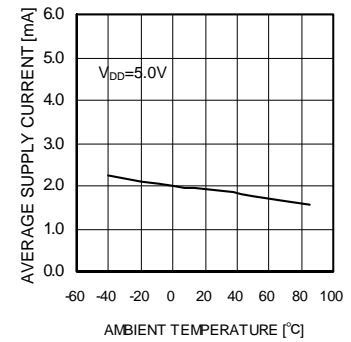
Fig.26　I$_{DD}$ – Ambient
temperature
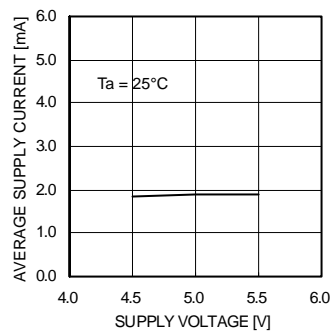
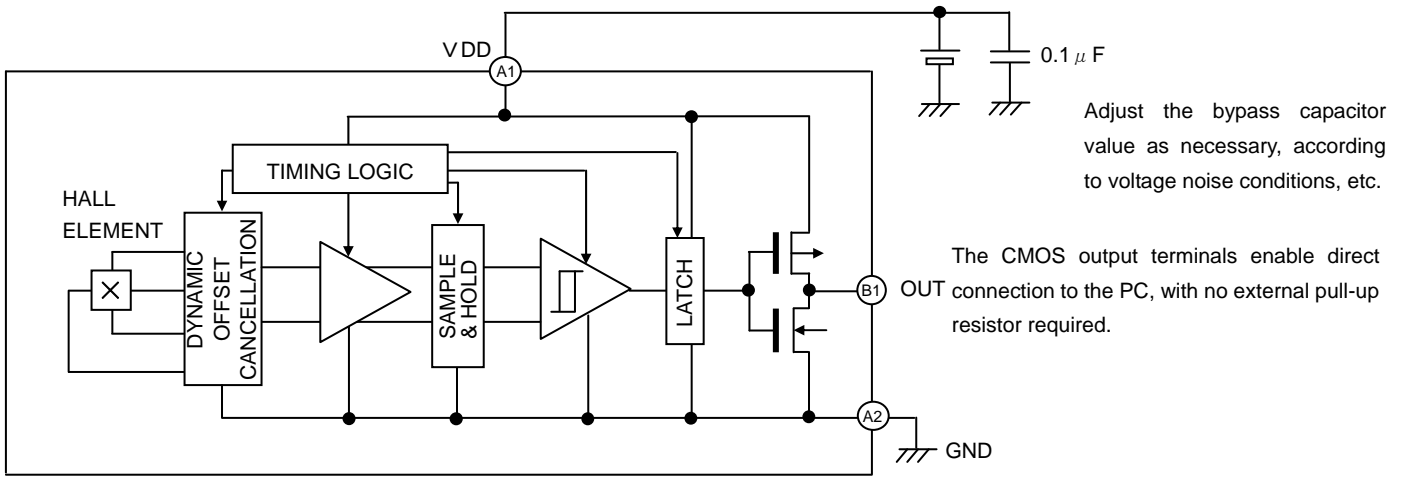Fig.27　I$_{DD}$ – Supply voltage

●Block Diagram
BU52001GUL

Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

Fig.28

PIN No.	PIN NAME	FUNCTION	COMMENT
A1	VDD	POWER SUPPLY	
A2	GND	GROUND	
B1	OUT	OUTPUT	
B2	N.C.		OPEN or Short to GND.

BU52015GUL

Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.
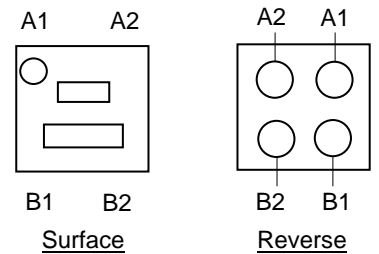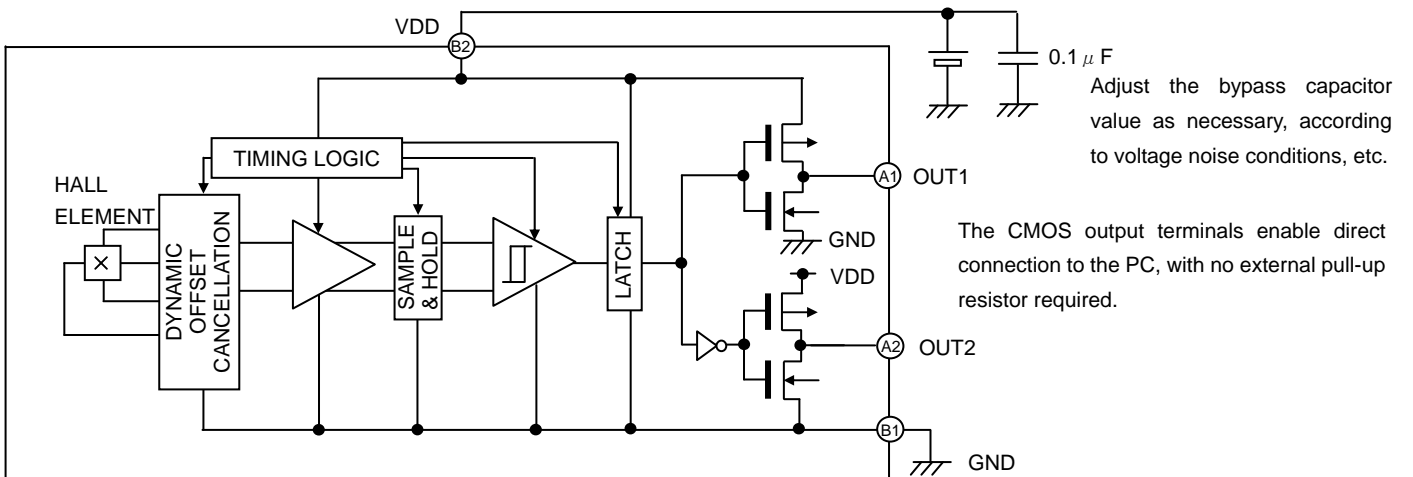
Fig.29

PIN No.	PIN NAME	FUNCTION	COMMENT
A1	OUT1	Output pin (Active Low)	
A2	OUT2	Output pin (Active High)	
B1	GND	GROUND	
B2	VDD	Power Supply Voltage	

BU52051NVX

VDD

0.1 μF

Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.
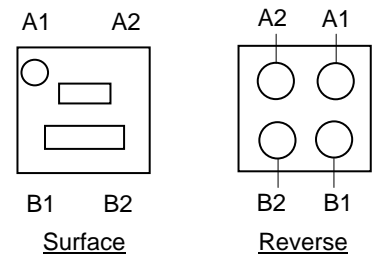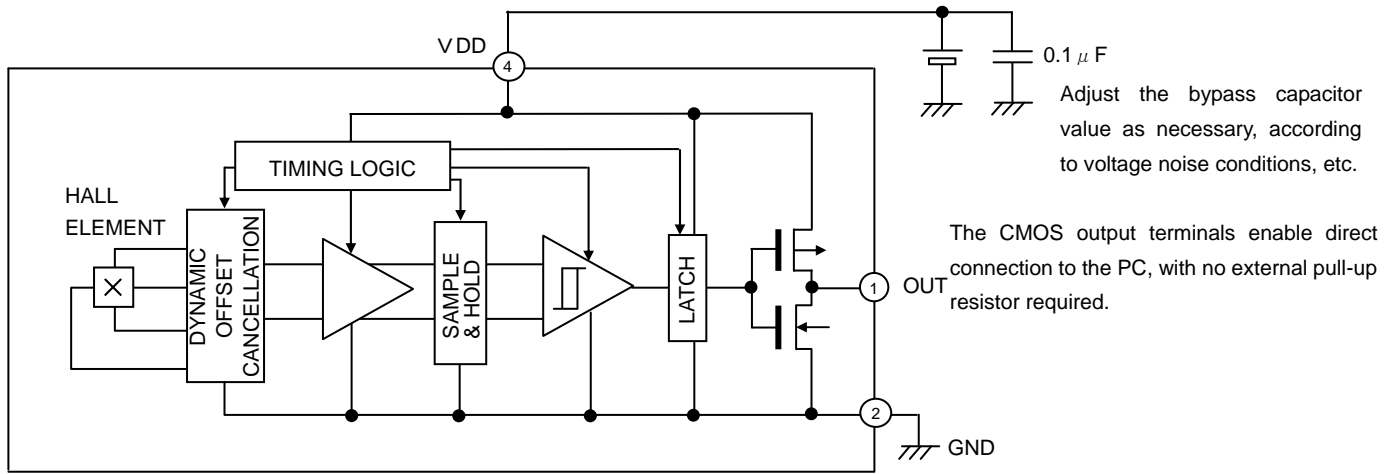
Fig.30

PIN No.	PIN NAME	FUNCTION	COMMENT
1	OUT	OUTPUT	
2	GND	GROUND	
3	N.C.		OPEN or Short to GND.
4	VDD	POWER SUPPLY	

4 3

1 2

Surface

3 4

2 1

Reverse

BU52011HFV,BU52021HFV

VDD

0.1 μF

Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

Fig.31

PIN No.	PIN NAME	FUNCTION	COMMENT
1	N.C.		OPEN or Short to GND.
2	GND	GROUND	
3	N.C.		OPEN or Short to GND.
4	VDD	POWER SUPPLY	
5	OUT	OUTPUT	

5   4

1 2 3

Surface

4   5

3 2 1

Reverse

BU52025G

Fig.32

Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

PIN No.	PIN NAME	FUNCTION	COMMENT
1	N.C.		OPEN or Short to GND.
2	GND	GROUND	
3	N.C.		OPEN or Short to GND.
4	VDD	POWER SUPPLY	
5	OUT	OUTPUT	

BD7411G
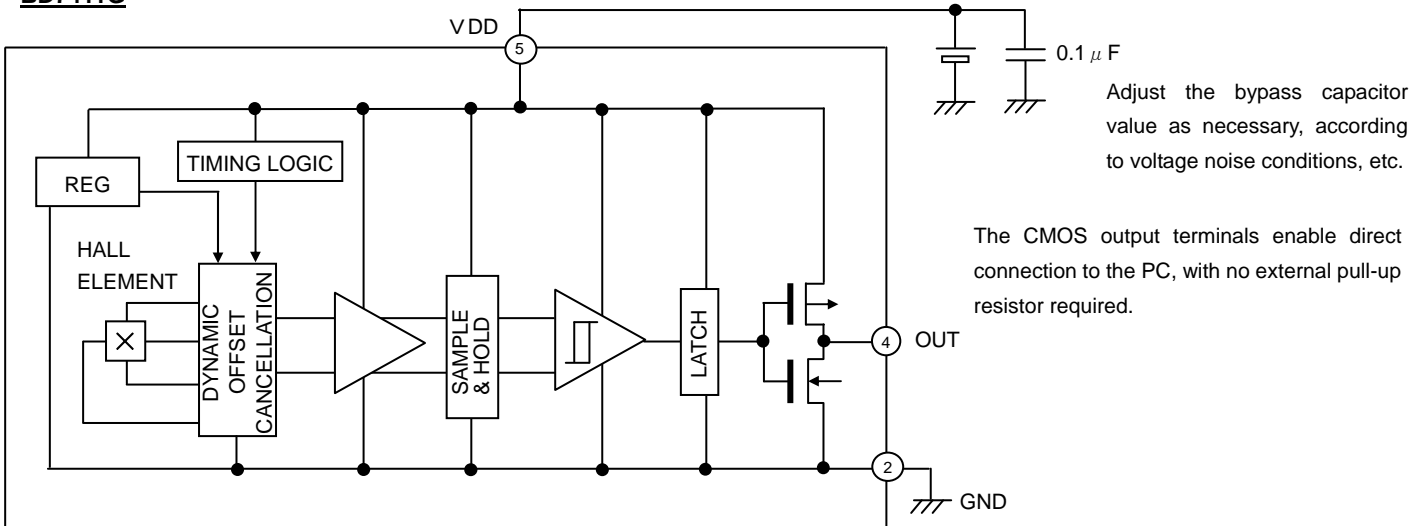
Fig.33

Adjust the bypass capacitor value as necessary, according to voltage noise conditions, etc.

The CMOS output terminals enable direct connection to the PC, with no external pull-up resistor required.

PIN No.	PIN NAME	FUNCTION	COMMENT
1	N.C.		OPEN or Short to GND.
2	GND	GROUND	
3	N.C.		OPEN or Short to GND.
4	OUT	OUTPUT	
5	VDD	POWER SUPPLY	
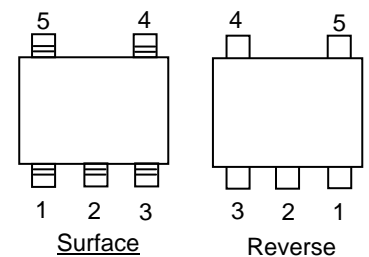
●Description of Operations

(Micropower Operation)
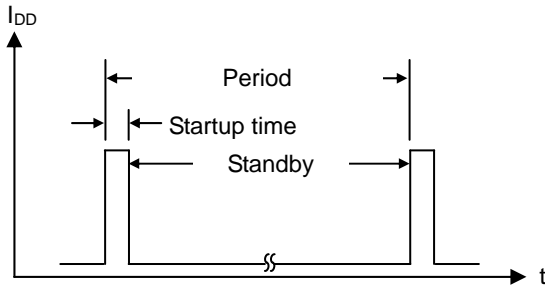
Fig.34

The bipolar detection Hall IC adopts an intermittent operation method to save energy. At startup, the Hall elements, amp, comparator and other detection circuits power ON and magnetic detection begins. During standby, the detection circuits power OFF, thereby reducing current consumption. The detection results are held while standby is active, and then output.

> Reference period: 50ms (MAX100ms)
> Reference startup time: 48 μ s

※BD7411G don't adopts an intermittent operation method.

(Offset Cancelation)
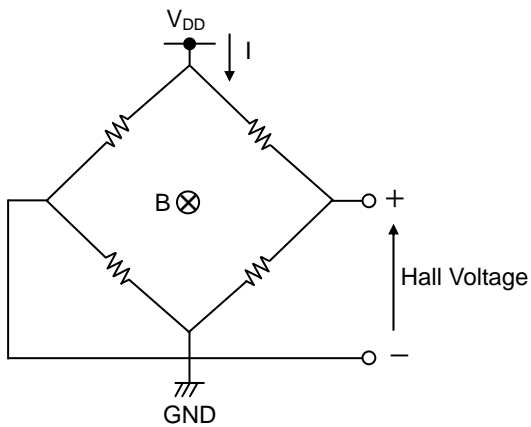
Fig.35

The Hall elements form an equivalent Wheatstone (resistor) bridge circuit. Offset voltage may be generated by a differential in this bridge resistance, or can arise from changes in resistance due to package or bonding stress. A dynamic offset cancellation circuit is employed to cancel this offset voltage.

When Hall elements are connected as shown in Fig. 35 and a magnetic field is applied perpendicular to the Hall elements, voltage is generated at the mid-point terminal of the bridge. This is known as Hall voltage.

Dynamic cancellation switches the wiring (shown in the figure) to redirect the current flow to a 90° angle from its original path, and thereby cancels the Hall voltage.

The magnetic signal (only) is maintained in the sample/hold circuit during the offset cancellation process and then released.
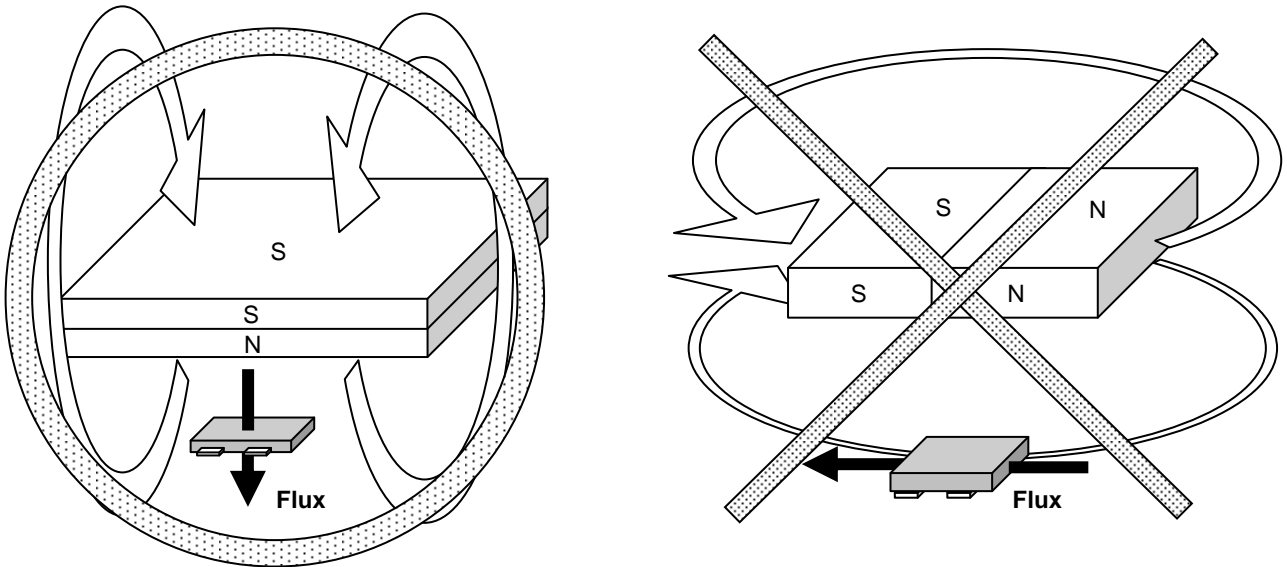
(Magnetic Field Detection Mechanism)

Fig.36

The Hall IC cannot detect magnetic fields that run horizontal to the package top layer.
Be certain to configure the Hall IC so that the magnetic field is perpendicular to the top layer.
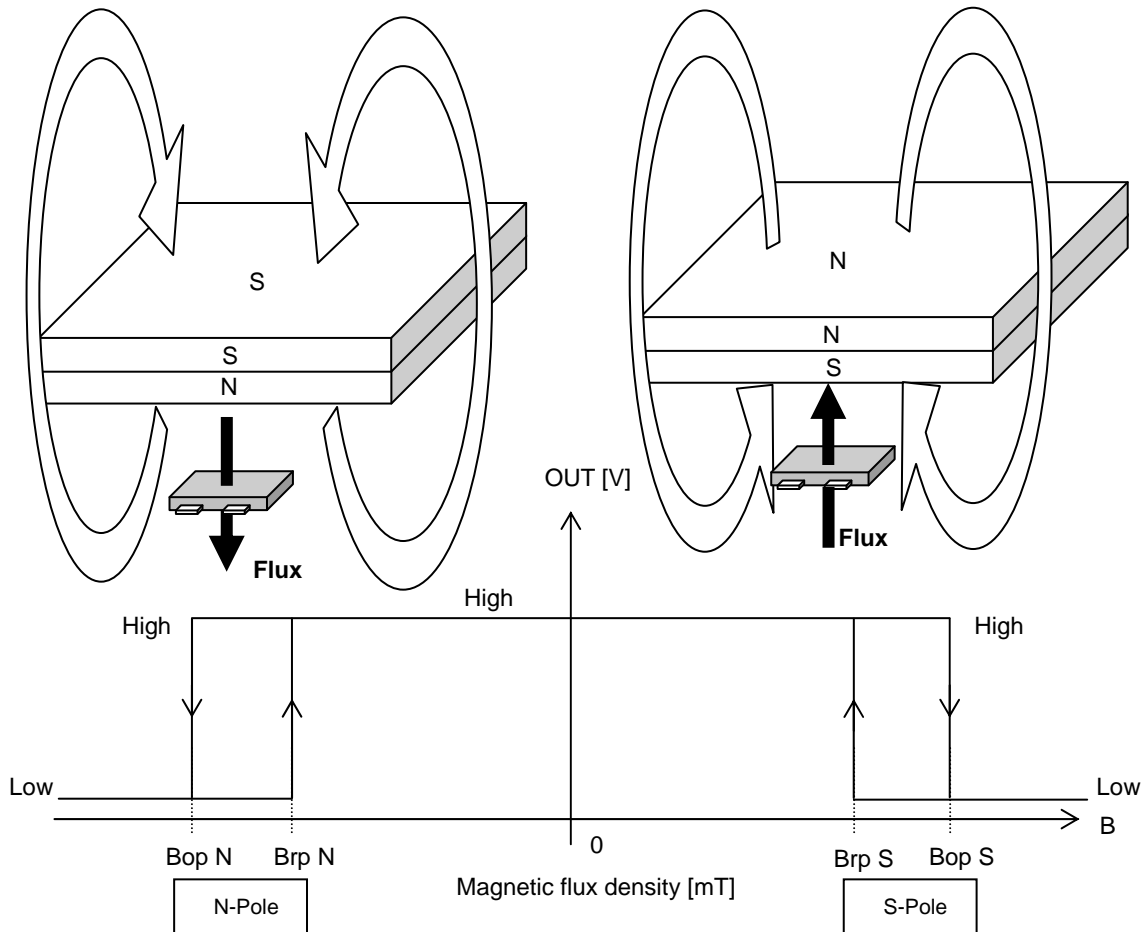

Fig.37

The bipolar detection Hall IC detects magnetic fields running perpendicular to the top surface of the package. There is an inverse relationship between magnetic flux density and the distance separating the magnet and the Hall IC: when distance increases magnetic density falls. When it drops below the operate point (Bop), output goes HIGH. When the magnet gets closer to the IC and magnetic density rises, to the operate point, the output switches LOW. In LOW output mode, the distance from the magnet to the IC increases again until the magnetic density falls to a point just below Bop, and output returns HIGH. (This point, where magnetic flux density restores HIGH output, is known as the release point, Brp.) This detection and adjustment mechanism is designed to prevent noise, oscillation and other erratic system operation.

● Intermittent Operation at Power ON

Power ON

VDD

Startup time — Standby time — Startup time — Standby time

Supply current
(Intermittent action)

OUT
(No magnetic
field present)

Indefinite — High

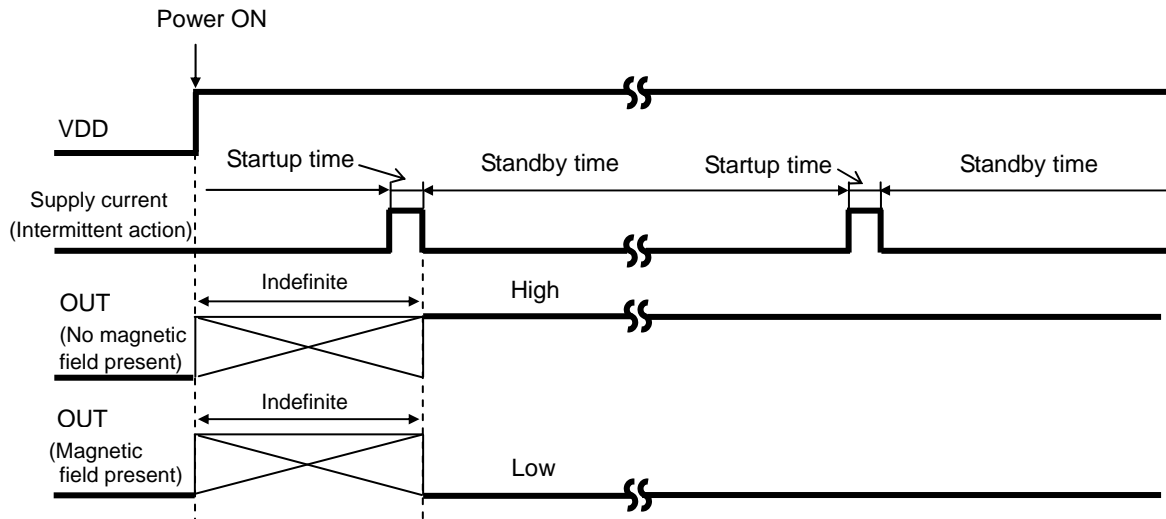OUT
(Magnetic
field present)

Indefinite — Low

Fig.38

The bipolar detection Hall IC adopts an intermittent operation method in detecting the magnetic field during startup, as shown in Fig. 38. It outputs to the appropriate terminal based on the detection result and maintains the output condition during the standby period. The time from power ON until the end of the initial startup period is an indefinite interval, but it cannot exceed the maximum period, 100ms. To accommodate the system design, the Hall IC output read should be programmed within 100ms of power ON, but after the time allowed for the period ambient temperature and supply voltage.
※BD7411G don't adopts an intermittent operation method.

● Magnet Selection

Of the two representative varieties of permanent magnet, neodymium generally offers greater magnetic power per volume than ferrite, thereby enabling the highest degree of miniaturization, Thus, neodymium is best suited for small equipment applications. Fig. 39 shows the relation between the size (volume) of a neodymium magnet and magnetic flux density. The graph plots the correlation between the distance (L) from three versions of a 4mm X 4mm cross-section neodymium magnet (1mm, 2mm, and 3mm thick) and magnetic flux density. Fig. 40 shows Hall IC detection distance – a good guide for determining the proper size and detection distance of the magnet. Based on the BU52011HFV, BU52015GUL operating point max 5.0 mT, the minimum detection distance for the 1mm, 2mm and 3mm magnets would be 7.6mm, 9.22mm, and 10.4mm, respectively. To increase the magnet's detection distance, either increase its thickness or sectional area.
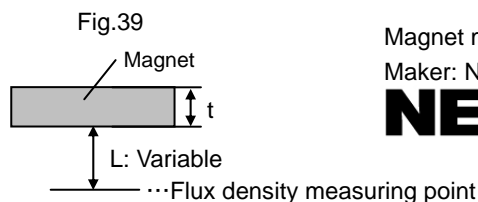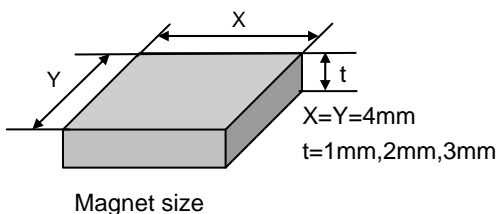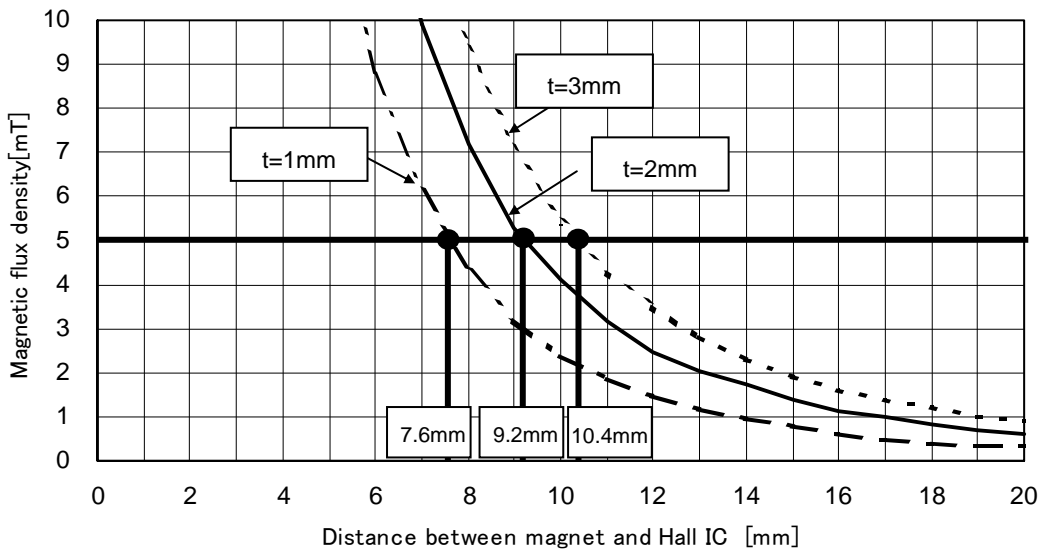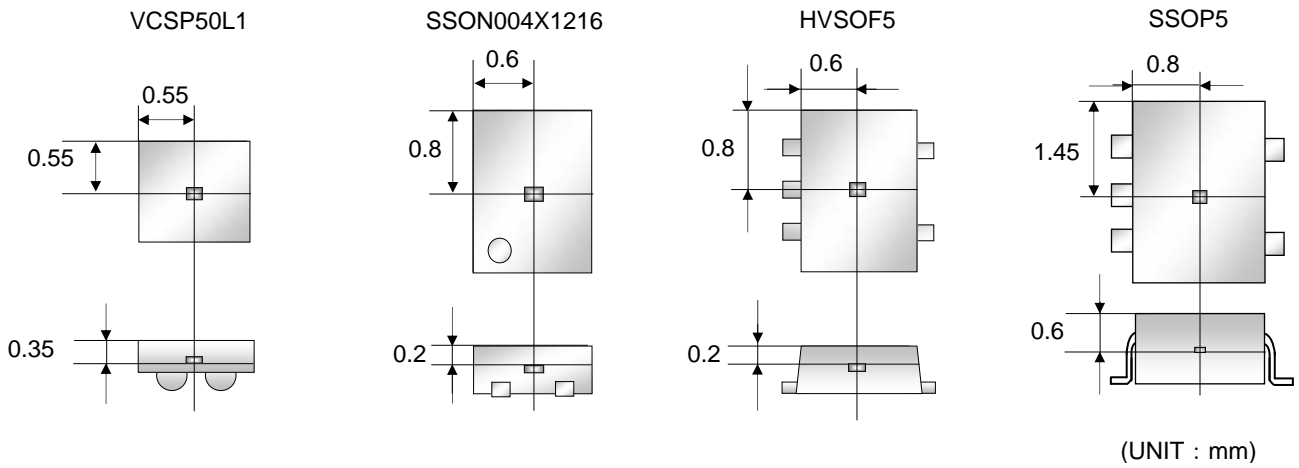
Magnetic flux density[mT]

t=3mm

t=1mm

t=2mm

7.6mm 9.2mm 10.4mm

Distance between magnet and Hall IC [mm]

Fig.39

X

Y

t

X=Y=4mm
t=1mm,2mm,3mm

Magnet size

Magnet

t

L: Variable

···Flux density measuring point

Magnet material: NEOMAX-44H (material)
Maker: NEOMAX CO.,LTD.

NEOMAX

Fig.40   Magnet Dimensions and
Flux Density Measuring Point

●Position of the Hall Effect IC(Reference)

VCSP50L1　　　　　SSON004X1216　　　　　HVSOF5　　　　　SSOP5

VCSP50L1:
0.55
0.55
0.35

SSON004X1216:
0.6
0.8
0.2

HVSOF5:
0.6
0.8
0.2

SSOP5:
0.8
1.45
0.6

(UNIT : mm)

●Footprint dimensions (Optimize footprint dimensions to the board design and soldering condition)

VCSP50L1

SD
e
b3
e
SE

Symbol	Reference Value
e	0.50
b3	0.25
SD	0.25
SE	0.25

SSON004X1216

0.65
0.22
0.4
0.6
0.7
0.85

Please be cautious to potential
stress from PCB material, strength,
mounting positions.
If you had any further questions
or concerns, please contact
your Rohm sales and affiliate.

HVSOF5

0.25   0.25
0.35   0.53   0.12
1.0   0.4
0.35   0.12
0.25   0.35
0.7
0.5   0.5

SSOP5

0.95   0.95
2.4
1.0
0.6

(UNIT : mm)

● Terminal Equivalent Circuit Diagram

OUT , OUT1, OUT2

VDD

GND
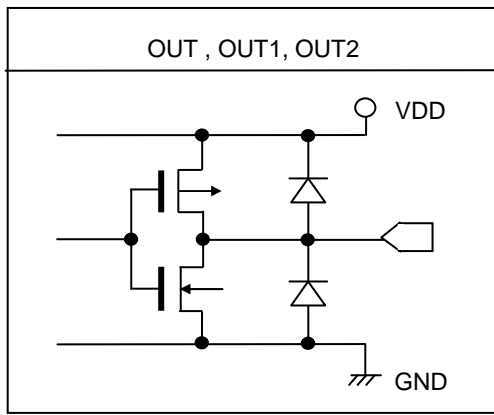
Fig.41

Because they are configured for CMOS (inverter) output, the output pins require no external resistance and allow direct connection to the PC. This, in turn, enables reduction of the current that would otherwise flow to the external resistor during magnetic field detection, and supports overall low current (micropower) operation.

● Operation Notes

1）Absolute maximum ratings

Exceeding the absolute maximum ratings for supply voltage, operating conditions, etc. may result in damage to or destruction of the IC. Because the source (short mode or open mode) cannot be identified if the device is damaged in this way, it is important to take physical safety measures such as fusing when implementing any special mode that operates in excess of absolute rating limits.

2) GND voltage

Make sure that the GND terminal potential is maintained at the minimum in any operating state, and is always kept lower than the potential of all other pins.

3) Thermal design

Use a thermal design that allows for sufficient margin in light of the power dissipation (Pd) in actual operating conditions.

4) Pin shorts and mounting errors

Use caution when positioning the IC for mounting on printed circuit boards. Mounting errors, such as improper positioning or orientation, may damage or destroy the device. The IC may also be damaged or destroyed if output pins are shorted together, or if shorts occur between the output pin and supply pin or GND.

5) Positioning components in proximity to the Hall IC and magnet

Positioning magnetic components in close proximity to the Hall IC or magnet may alter the magnetic field, and therefore the magnetic detection operation. Thus, placing magnetic components near the Hall IC and magnet should be avoided in the design if possible. However, where there is no alternative to employing such a design, be sure to thoroughly test and evaluate performance with the magnetic component(s) in place to verify normal operation before implementing the design.

6) Slide-by position sensing

Fig.42 depicts the slide-by configuration employed for position sensing. Note that when the gap (d) between the magnet and the Hall IC is narrowed, the reverse magnetic field generated by the magnet can cause the IC to malfunction. As seen in Fig.43, the magnetic field runs in opposite directions at Point A and Point B. Since the bipolar detection Hall IC can detect the S-pole at Point A and the N-pole at Point B, it can wind up switching output ON as the magnet slides by in the process of position detection. Fig. 44 plots magnetic flux density during the magnet slide-by. Although a reverse magnetic field was generated in the process, the magnetic flux density decreased compared with the center of the magnet. This demonstrates that slightly widening the gap (d) between the magnet and Hall IC reduces the reverse magnetic field and prevents malfunctions.
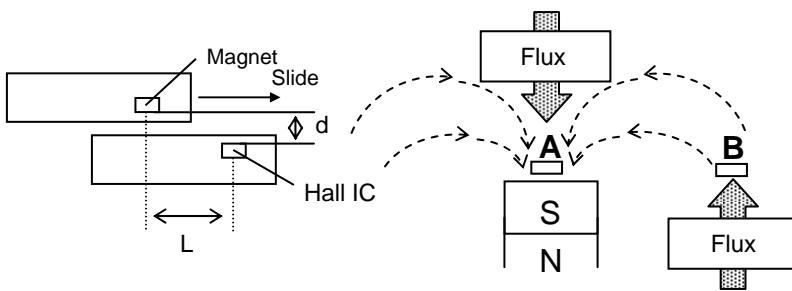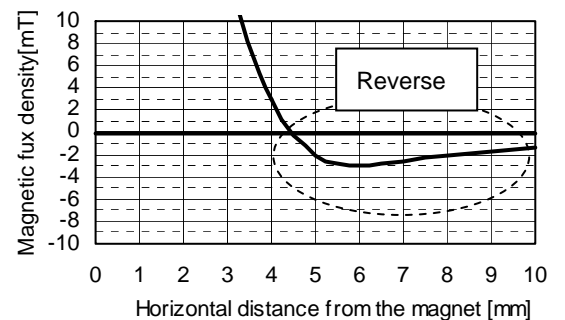

Fig.42

Fig.43

Fig.44

7) Operation in strong electromagnetic fields

Exercise extreme caution about using the device in the presence of a strong electromagnetic field, as such use may cause the IC to malfunction.

8) Common impedance

Make sure that the power supply and GND wiring limits common impedance to the extent possible by, for example, employing short, thick supply and ground lines. Also, take measures to minimize ripple such as using an inductor or capacitor.

9) GND wiring pattern

When both a small-signal GND and high-current GND are provided, single-point grounding at the reference point of the set PCB is recommended, in order to separate the small-signal and high-current patterns, and to ensure that voltage changes due to the wiring resistance and high current do not cause any voltage fluctuation in the small-signal GND. In the same way, care must also be taken to avoid wiring pattern fluctuations in the GND wiring pattern of external components.

10) Exposure to strong light

Exposure to halogen lamps, UV and other strong light sources may cause the IC to malfunction. If the IC is subject to such exposure, provide a shield or take other measures to protect it from the light. In testing, exposure to white LED and fluorescent light sources was shown to have no significant effect on the IC.

11) Power source design

Since the IC performs intermittent operation, it has peak current when it's ON. Please taking that into account and under examine adequate evaluations when designing the power source.

●Product Designations (Selecting a model name when ordering)

| B | U | | 5 | 2 | 0 | 0 | 1 | | G | U | L | — | E | 2 |

ROHM model   Part number   Package type   E2 = Reel-wound embossed taping

VSCP50L1	: GUL
SSON004X1216	: NVX
HVSOF5	: HFV
SSOP5	: G
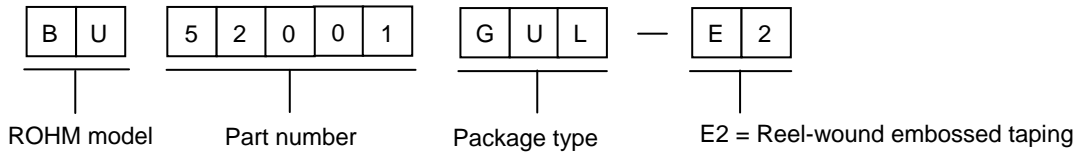
VSCP50L1	: E2
SSON004X1216	: TR
HVSOF5	: TR
SSOP5	: TR

VCSP50L1

<Dimensions>
(Unit: mm)

< Tape/Reel Info >

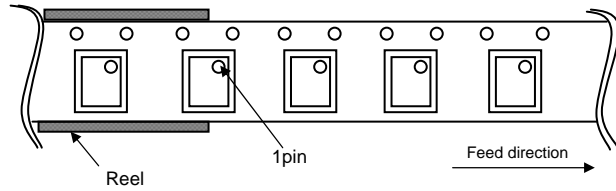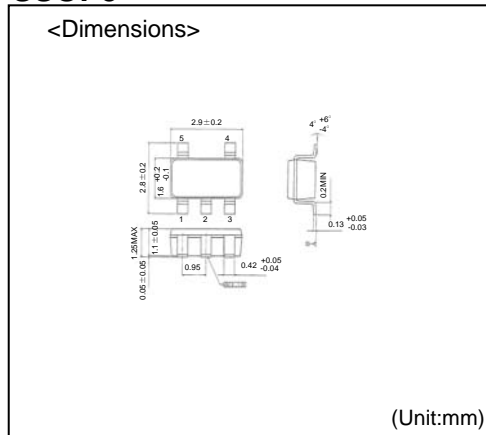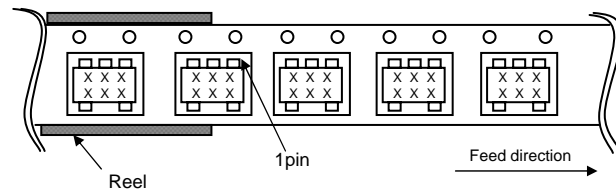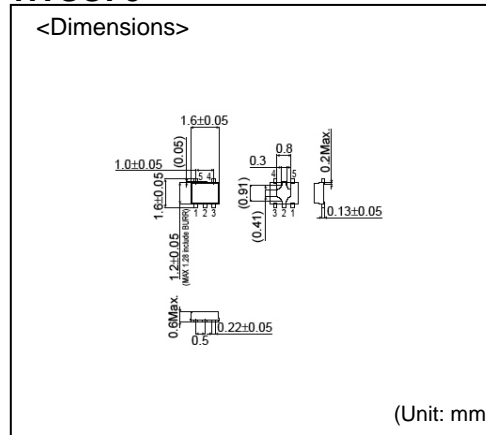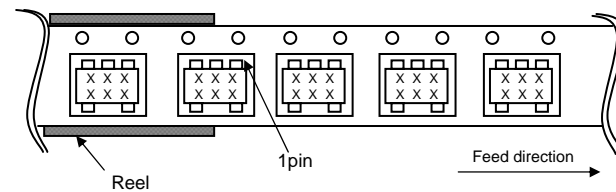| Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	E2 (Correct direction: With reel in the left hand, the 1pin of the product should be at the upper left. Pull tape out with the right hand)

Reel   1pin   Direction of feed

※Orders are available in complete units only.

SSON004X1216

<Dimensions>

1.2±0.1

1.6±0.1

1PIN MARK

0.6MAX

0.08 S

0.02 +0.03 -0.02 (0.12)

0.65±0.1

0.2 +0.05 -0.04

0.2±0.1

0.8±0.1

0.75±0.1

(Unit:mm)
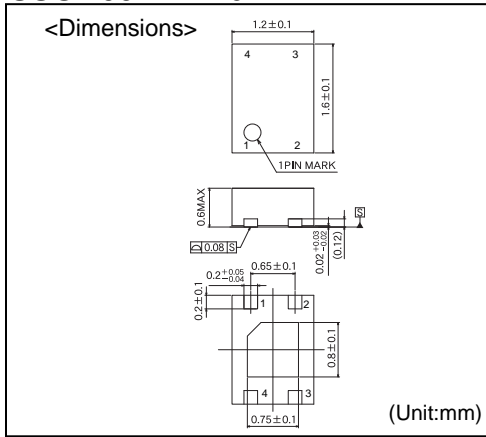
< Tape/Reel Info >

Tape	Embossed carrier tape
Quantity	5000pcs
Direction of feed	TR (Correct direction: With reel in the left hand, the 1pin of the product should be at the upper left. Pull tape out with the right hand)

Reel

1pin

Feed direction

※Orders are available in complete units only.

SSOP5

<Dimensions>

2.9±0.2

2.8±0.2

1.6 +0.2 -0.1

4° +6° -4°

0.2MIN

0.13 +0.05 -0.03

1.25MAX

1.1±0.05

0.05±0.05

0.95

0.42 +0.05 -0.04

(Unit:mm)

< Tape/Reel Info >

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (Correct direction: With reel in the left hand, the 1pin of the product should be at the upper left. Pull tape out with the right hand)

Reel

1pin

Feed direction

※Orders are available in complete units only.

HVSOF5

<Dimensions>

1.6±0.05

(0.05)

1.0±0.05

0.8

0.3

0.2Max

1.6±0.05

(0.91)

(0.41)

0.13±0.05

1.2±0.05 (MAX 1.28 include BURR)

0.6Max.

0.22±0.05

0.5

(Unit: mm)

< Tape/Reel Info >

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	TR (Correct direction: With reel in the left hand, the 1pin of the product should be at the upper left. Pull tape out with the right hand)

Reel

1pin

Feed direction

※Orders are available in complete units only.

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Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

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Salo	TEL: +358-2-7332234	FAX: +358-2-7332237
Oulu	TEL: +358-8-5372930	FAX: +358-8-5372931
Barcelona	TEL: +34-9375-24320	FAX: +34-9375-24410
Hungary	TEL: +36-1-4719338	FAX: +36-1-4719339
Poland	TEL: +48-22-5757213	FAX: +48-22-5757001
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Shanghai	TEL: +86-21-6279-2727	FAX: +86-21-6247-2066
Hangzhou	TEL: +86-571-87658072	FAX: +86-571-87658071
Nanjing	TEL: +86-25-8689-0015	FAX: +86-25-8689-0393
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Zhuhai	TEL: +86-756-3232-480	FAX: +86-756-3232-460
Hong Kong	TEL: +852-2-740-6262	FAX: +852-2-375-8971
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Philippines	TEL: +63-2-807-6872	FAX: +63-2-809-1422
Thailand	TEL: +66-2-254-4890	FAX: +66-2-256-6334
Kuala Lumpur	TEL: +60-3-7958-8355	FAX: +60-3-7958-8377
Penang	TEL: +60-4-2286453	FAX: +60-4-2286452
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